TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCX86FT, TC74VCX86FK

Low-Voltage Quad 2-Input Exclusive OR Gate with 3.6-V Tolerant Inputs and Outputs

The TC74VCX86FT/FK is a high- performance CMOS exclusive OR gate which is guaranteed to operate from 1.2-V to 3.6-V. Designed for use in 1.5V, 1.8V, 2.5V or 3.3V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs

All inputs are equipped with protection circuits against static discharge.

Features

Low-voltage operation: VCC = 1.2 to 3.6 V

High-speed operation : $t_{pd} = 3.0 \text{ ns (max)} (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$

 $t_{pd} = 3.9 \text{ ns (max) (VCC} = 2.3 \text{ to } 2.7 \text{ V)}$

 $t_{pd} = 7.8 \text{ ns (max) (VCC} = 1.65 \text{ to } 1.95 \text{ V)}$

 $t_{pd} = 15.6 \text{ ns (max) (V}_{CC} = 1.4 \text{ to } 1.6 \text{ V}$

 $t_{pd} = 39.0 \text{ ns (max) (VCC} = 1.2 \text{ V)}$

Output current: $I_{OH}/I_{OL} = \pm 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$

 $I_{OH}/I_{OL} = \pm 18 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$

 $: I_{OH}/I_{OL} = \pm 6 \text{ mA (min)} (V_{CC} = 1.65 \text{ V})$

: $I_{OH}/I_{OL} = \pm 2$ mA (min) ($V_{CC} = 1.4$ V)

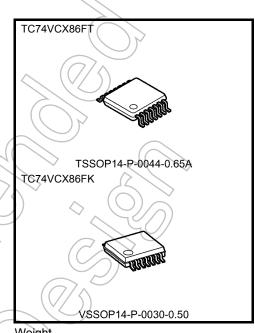
Latch-up performance: -300 mA

ESD performance: Machine model $\geq \pm 200 \text{ V}$

Human body model ≥ ±2000 V

Package: TSSOP and VSSOP (US)

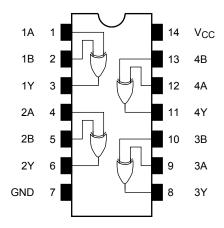
Power-down protection provided on all inputs and outputs



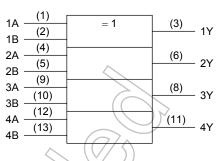
Weight

TSSOP14-P-0044-0.65A : 0.06g (typ.) VSSØP14-P-0030-0.50 : 0.02 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Α	В	Υ
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vec	-0.5 to 4.6	V
DC input voltage	(VIN)	-0.5 to 4.6	V
DC output voltage	Vout	-0.5 to 4.6 (Note 2) -0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	lik	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	Pp	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: $V_{CC} = 0 V$

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: Vout < GND, Vout > Vcc

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	1.2 to 3.6	V	
Input voltage	V _{IN}	-0.3 to 3.6	V	
Output voltage	Vout	0 to 3.6 (Note 2)	V	
Output voltage	٧٥٥١	0 to V _{CC} (Note 3)	V	
		±24 (Note 4)		
Output current	I _{OH} /I _{OI}	±18 (Note 5)	m4	
Output current	IOH/IOL	±6 (Note 6)	mA (
		±2 (Note 7)		
Operating temperature	T _{opr}	-40 to 85	(°C)	
Input rise and fall time	dt/dv	0 to 10 (Note 8)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device: Unused inputs must be tied to either V_{CC} or GND.

Note 2: $V_{CC} = 0 V$

Note 3: High or low state

Note 4: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 5: $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$

Note 6: $V_{CC} = 1.65 \text{ to } 1.95 \text{ V}$ Note 7: $V_{CC} = 1.4 \text{ to } 1.6 \text{ V}$

Note 8: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C, 2.7 V < V_{CC} \le 3.6 V)

Characteris	stics	Symbol	Test Coi	ndition		Min	Max	Unit
				31)	V _{CC} (V)			
Input voltage	"H" level	VIH	/	<u>-</u>	2.7 to 3.6	2.0	_	V
input voltage	"L" level	VIL		<i>!)</i>	2.7 to 3.6		0.8	V
		\rightarrow		$I_{OH} = -100 \mu A$	2.7 to 3.6	V _{CC} - 0.2	_	
	"H" level	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	
Z			\wedge	$I_{OH} = -18 \text{ mA}$	3.0	2.4	_	
Output voltage			9	$I_{OH} = -24 \text{ mA}$	3.0	2.2	_	V
))			$I_{OL} = 100 \mu A$	2.7 to 3.6	_	0.2	
	"L" level	Vol	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 12 mA	2.7	_	0.4	
	Lievei	VOL	VIN - VIH OI VIL	$I_{OL} = 18 \text{ mA}$	3.0		0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage curren	nt	I _{IN}	$V_{IN} = 0$ to 3.6 V		2.7 to 3.6		±5.0	μΑ
Power off leakage co	urrent	loff	V_{IN} , $V_{OUT} = 0$ to 3.6 V		0		10.0	μΑ
Quioscont supply ou	rront	laa	$V_{IN} = V_{CC}$ or GND		2.7 to 3.6		20.0	
Quiescent supply cu	IIICIIL	Icc	V _{CC} ≤ V _{IN} ≤ 3.6 V		2.7 to 3.6	_	±20.0	μА
Increase in I _{CC} per i	nput	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6		750	

DC Characteristics (Ta = -40 to 85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteristics		Symbol	Test Cor	ndition		Min	Max	Unit
					V _{CC} (V)			
Input voltage	H-level	V _{IH}	_	-	2.3 to 2.7	1.6	_	V
input voitage	L-level	V _{IL}	_	-	2.3 to 2.7		0.7	V
				$I_{OH} = -100 \mu A$	2.3 to 2.7	V _{CC} - 0.2		
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -6 mA	2.3	2.0	_	V
				I _{OH} = -12 mA	2.3	1.8	_	
Output voltage				$I_{OH} = -18 \text{ mA}$	2.3	1.7	_	
				I _{OL} = 100 μA	2.3 to 2.7		0.2	
	L-level	V _{OL}	<u> </u>	I _{OL} = 12 mA	2.3		0.4	
				I _{OL} = 18 mA	2.3	4	0.6	
Input leakage curre	nt	I _{IN}	$V_{IN} = 0$ to 3.6 V		2.3 to 2.7		±5.0	μΑ
Power-off leakage of	current	I _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6 V	(0)	0		10.0	μΑ
Quiescent supply cu	ırrent	loo	V _{IN} = V _{CC} or GND		2.3 to 2.7	14	20.0	Δ
Quiescent supply co	an ent	ICC	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		2.3 to 2.7		±20.0	μА

DC Characteristics (Ta = -40 to 85°C, 1.65 V \leq V_{CC} < 2.3 V)

Characteris	stics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Innut voltage	H-level	V _{IH}	-	1.65 to 2.3	0.65 × V _{CC}	_	V
Input voltage L-lev	L-level	VIL	- \	1.65 to 2.3	_	0.2 × V _{CC}	V
 -	H-level	Уон	V _{IN} = V _{IH} or V _{IL}	1.65 to 2.3	V _{CC} - 0.2	_	
Output voltage			10H = -6 mA	1.65	1.25	_	V
	L-Jevel	1/2:	V _{IN} = V _{IH} or V _{IL}	1.65 to 2.3	_	0.2	
	L-level	VoL	I _{OL} = 6 mA	1.65	_	0.3	
Input leakage currer	nt	I _{IN}	V _{IN} = 0 to 3.6 V	1.65 to 2.3	_	±5.0	μА
Power-off leakage co	urrent	I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V	0	_	10.0	μА
Outros and a complex of the complex	(ront)		V _{IN} = V _{CC} or GND	1.65 to 2.3	_	20.0	^
Quiescent supply cu	TEUL	Icc	V _{CC} ≤ V _{IN} ≤ 3.6 V	1.65 to 2.3	_	±20.0	μА

DC Characteristics (Ta = -40 to 85°C, 1.4 V \leq V_CC < 1.65 V)

Characteris	stics	Symbol	Test Cor	ndition	V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	_	-	1.4 to 1.65	0.65 × V _{CC}		٧
Input voltage L-level	L-level	V _{IL}	_		1.4 to 1.65	1/2	0.2 × V _{CC}	V
	H-level	H-level V _{OH}	V _{OH} V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -100 \mu A$	1.4 to 1.65	V _{CC} - 0.2		
Output voltage					I _{OH} = -2 mA	(1.4)	1.05	
	L-level	laval V	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.4 to 1.65		0.05	
	L-level	V _{OL}	VIN — VIH OI VIL	I _{OL} = 2 mA)) 1.4		0.35	
Input leakage currer	nt	I _{IN}	V _{IN} = 0 to 3.6 V		1.4 to 1.65		±5.0	μА
Power-off leakage of	urrent	l _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6 V		0	17	10.0	μА
Quiescent supply current		loo	V _{IN} = V _{CC} or GND		1.4 to 1.65	7-//	> 20.0	
Quiescent supply co	ii i Ci i (ICC	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		1.4 to 1.65	7/	±20.0	μА

DC Characteristics (Ta = -40 to 85°C, 1.2 V \leq V_{CC} < 1.4 V)

Characteris	stics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Innut voltage	H-level	V _{IH}	- ()	1.2 to 1.4	0.8 × V _{CC}		V
Input voltage	L-level	VIL	- ~	1.2 to 1.4	_	0.05 × V _{CC}	V
Output voltage	H-level	VoH	V _{IN} = V _{JH} or V _{IL} 1 _{OH} = -100 µA	1.2	V _{CC} - 0.1	_	V
	L-level	VOL	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 100 \mu\text{A}$	1.2	_	0.05	
Input leakage currer	nt /) HN	V _{IN} = 0 to 3.6 V	1.2	_	±5.0	μΑ
Power-off leakage c	urrent	IOFF/	V_{IN} , $V_{OUT} = 0$ to 3.6 V	0	_	10.0	μΑ
Quiescent supply current		loo	V _{IN} = V _{CC} or GND	1.2	_	20.0	Δ
Quiescent supply co	ment	\ \loc	V _{CC} ≤ V _{IN} ≤ 3.6 V	1.2	_	±20.0	μА

AC Characteristics (Ta = -40 to 85° C, input: $t_r = t_f = 2.0$ ns) (Note)

Characteristics	Symbol	Test	V _{CC} (V)	Min	Max	Unit	
Propagation delay time		Figure 1, Figure 2	C _L = 15 pF, R _L = 2 kΩ	1.2	1.5	39.0	
	.		OL = 13 pi , IVL = 2 K12	1.5 ± 0.1	1.0	15.6	
	t _{pLH} t _{pHL}		$C_L = 30 \text{ pF}, R_L = 500 \Omega$	1.8 ± 0.15	1.5	7.8	ns
				2.5 ± 0.2	0.8	3.9	
				3.3 ± 0.3	0.6	3.0	

Note: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition	,	Vcc (V)	Тур.	Unit
Outot outout mayimum dunamia V	V	V _{IH} = 1.8 V, V _{IL} = 0 V	(Note)	1.8	0.25	V
Quiet output maximum dynamic V _{OL}	V _{OLP}	V _{IH} = 2.5 V, V _{IL} = 0 V V _{IH} = 3.3 V, V _{IL} = 0 V	(Note) (Note)	2.5	0.6	V
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note)	1.8	-0.25	
Quiet output minimum dynamic V _{OL}	V _{OLV}	$V_{IH} = 2.5 V$, $V_{IL} = 0 V$	(Note)	2.5	-0.6	V
		$V_{IH} = 3.3 V, V_{IL} = 0 V$	(Note)	3.3	-0.8	
Quiet output minimum dynamic V _{OH}		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	1.8	1.5	
	V _{OHV}	$V_{1H} = 2.5 \text{ V}, V_{1L} = 0 \text{ V}$	(Note)	2.5	1.9	V
		V _{IH} = 3.3 V, V _{IL} = 0 V	(Note)	3.3	2.2	

Note: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_	1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	C _{PD}	$f_{\text{IN}} = 10 \text{ MHz}$ (Note) 1.8, 2.5, 3.3	20	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

6

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$

2014-03-01

AC Test Circuit

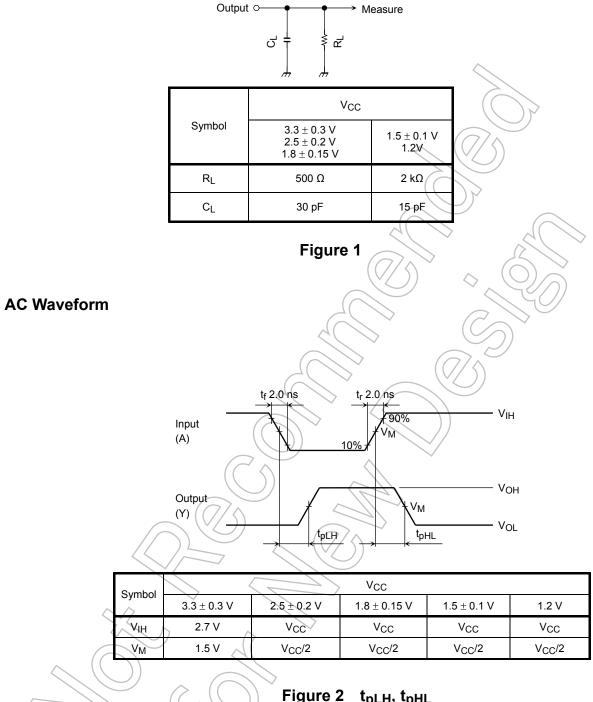
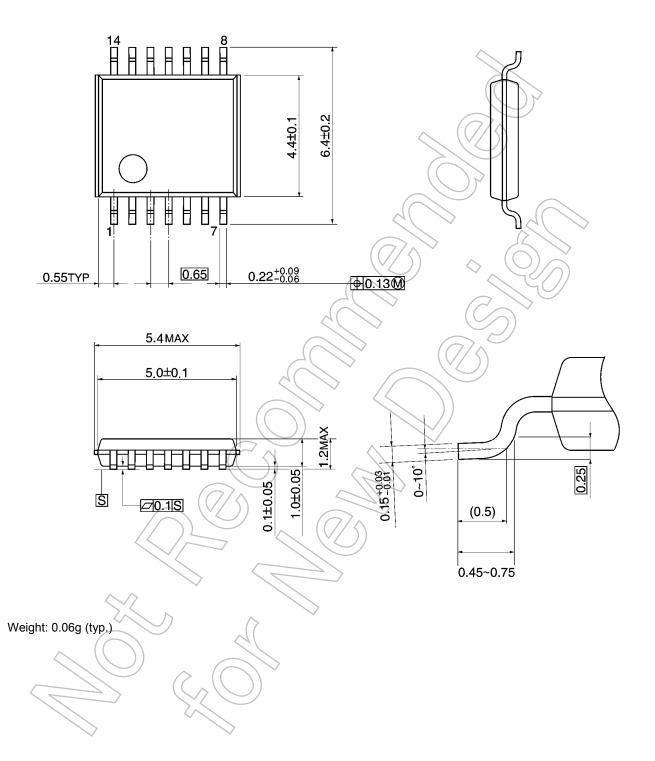


Figure 2 t_{pLH}, t_{pHL}

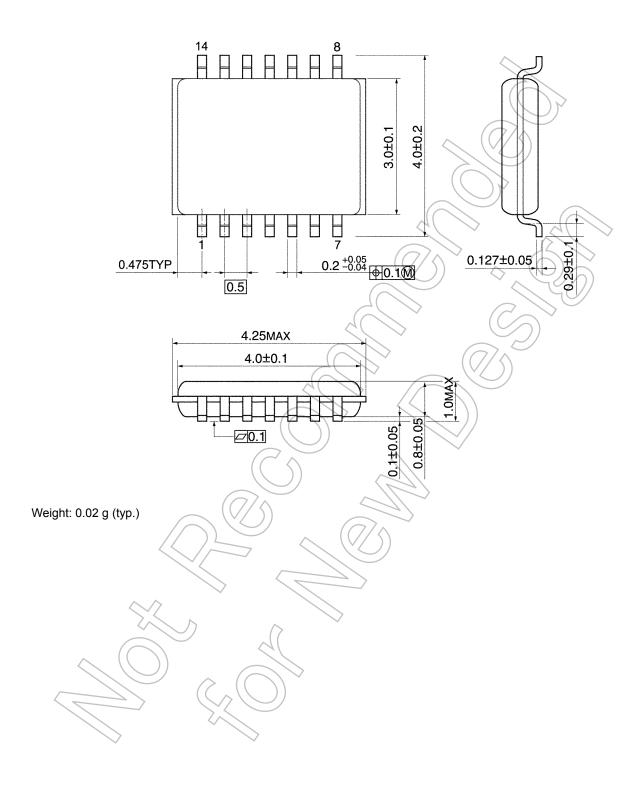
Package Dimensions

TSSOP14-P-0044-0.65A Unit: mm



Package Dimensions

VSSOP14-P-0030-0.50 Unit: mm



RESTRICTIONS ON PRODUCT USE

- Toshiba Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE
 EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH
 MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT
 ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without
 limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, medical equipment, equipment used for
 automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions,
 safety devices, elevators and escalators, devices related to electric power, and equipment used in finance-related fields. IF YOU USE
 PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your
 TOSHIBA sales representative.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
 applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
 FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY
 WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR
 LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND
 LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO
 SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS
 FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
 Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES
 OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.